

D₁
CONCL. a circuit for driving said first thin film transistors, said circuit comprising third thin film transistors formed over said substrate,

wherein each of said light emissive elements comprises an organic electroluminescent material.

5.
14. (Amended) An active matrix type organic luminescent display device comprising:

a substrate;

at least one first signal line and one second signal line formed over said substrate, said at least one first signal line and one second signal intersecting each other over said substrate;

D₂ a first thin film transistor formed over said substrate, wherein said first signal line is connected to a gate of said first thin film transistor and said second signal line is connected to a source or drain of the first thin film transistor;

a second thin film transistor formed over said substrate wherein the other one of the source or drain of the first thin film transistor is connected to a gate of the second thin film transistor;

an organic electroluminescent element formed over said substrate and electrically connected to a source or drain of said second thin film transistor;

a power supply line electrically connected to the other one of the source or drain of the second thin film transistor; and

a circuit for driving said first thin film transistor, said circuit comprising third thin film transistors formed over said substrate.

9.
14. (Amended) An active matrix type organic luminescent display device comprising:

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a substrate;

at least one first signal line and one second signal line formed over said substrate, said at least one first signal line and one second signal intersecting each other over said substrate;

a first thin film transistor formed over said substrate, wherein said first signal line is connected to a gate of said first thin film transistor and said second signal line is connected to a source or drain of the first thin film transistor;

a second thin film transistor formed over said substrate, wherein the other one of the source or drain of the first thin film transistor is connected to a gate of the second thin film transistor;

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cancel. an organic electroluminescent element formed over said substrate and electrically connected to a source or drain of said second thin film transistor;

a power supply line electrically connected to the other one of the source or drain of the second thin film transistor;

a capacitor formed between the gate of the second thin film transistor and the source or drain of the second thin film transistor to which said power supply line is connected; and

a circuit for driving said first thin film transistor, said circuit comprising third thin film transistors formed over said substrate.

14.
~~21.~~ (Amended) An active matrix type organic luminescent display device comprising:

a substrate;

D4 at least one first signal line and one second signal line formed over said substrate, said at least one first signal line and one second signal intersecting each other over said substrate;

a first thin film transistor formed over said substrate, wherein said first signal line is connected to a gate of said first thin film transistor and said second signal line is connected to a source or drain of the first thin film transistor;

a second thin film transistor formed over said substrate, wherein the gate of said second thin film transistor is electrically connected to said second signal line through said first thin film transistor;

an organic electroluminescent element formed over said substrate;

a power supply line electrically connected to said organic electroluminescent element through said second thin film transistor; and

a circuit for driving said first thin film transistors, said circuit comprising third thin film transistors formed over said substrate.

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~~24~~ (Amended) An active matrix type organic luminescent display device comprising:

a substrate;

at least one first signal line and one second signal line formed over said substrate, said at least one first signal line and one second signal intersecting each other over said substrate;

a first thin film transistor formed over said substrate, wherein said first signal line is connected to a gate of said first thin film transistor;

a second thin film transistor formed over said substrate, wherein a gate of said second thin film transistor is electrically connected to said second signal line through said first thin film transistor;

an organic electroluminescent element formed over said substrate;

a power supply line formed over said substrate and electrically connected to said organic electroluminescent element through said second thin film transistor;